

2SB1371

Silicon PNP triple diffusion planar type

For high power amplification
Complementary to 2SD2064

■ Features

- Excellent collector current I_C characteristics of forward current transfer ratio h_{FE}
- Wide safe operation area
- High transition frequency f_T
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	−120	V
Collector-emitter voltage (Base open)	V_{CEO}	−120	V
Emitter-base voltage (Collector open)	V_{EBO}	−5	V
Collector current	I_C	−6	A
Peak collector current	I_{CP}	−10	A
Collector power dissipation	P_C	70	W
		3	
$T_a = 25^{\circ}\text{C}$			
Junction temperature	T_j	150	$^{\circ}\text{C}$
Storage temperature	T_{stg}	−55 to +150	$^{\circ}\text{C}$

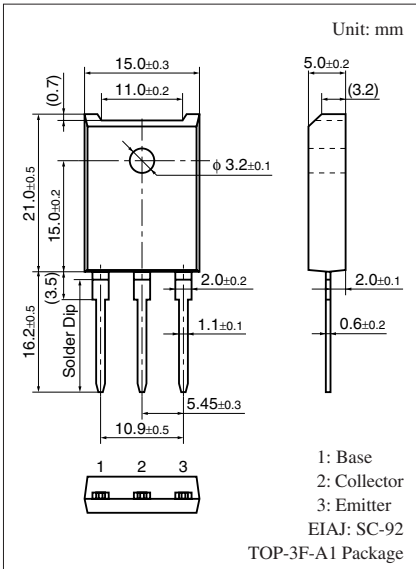
■ Electrical Characteristics $T_C = 25^\circ\text{C} \pm 3^\circ\text{C}$

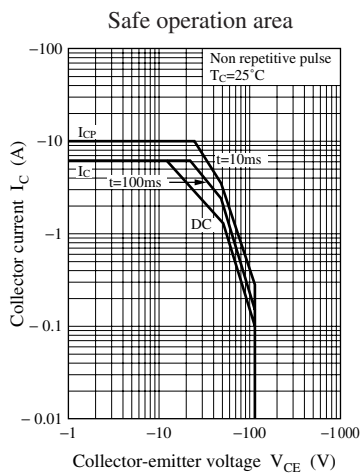
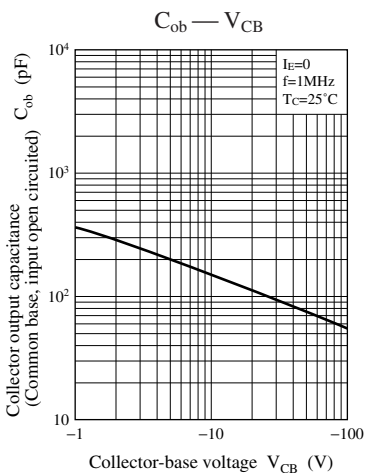
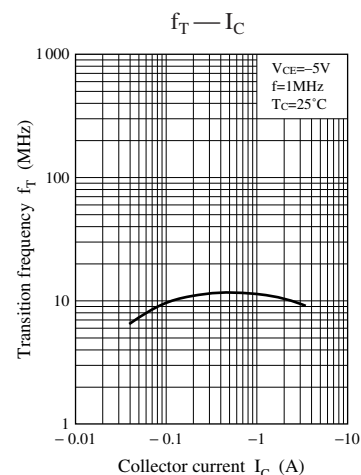
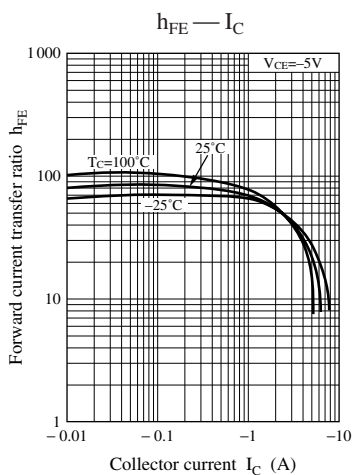
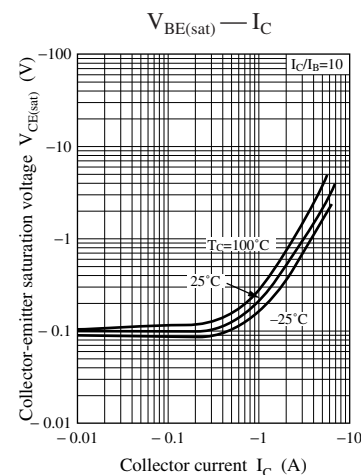
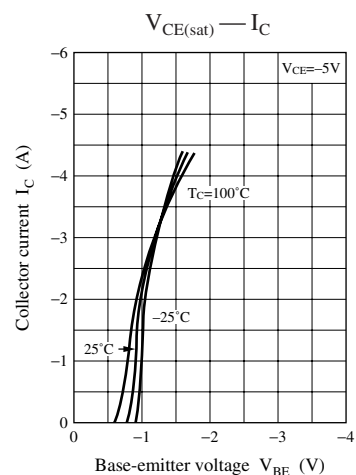
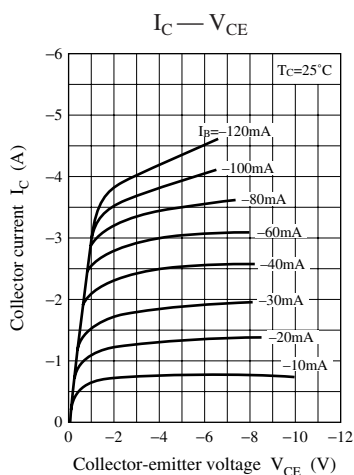
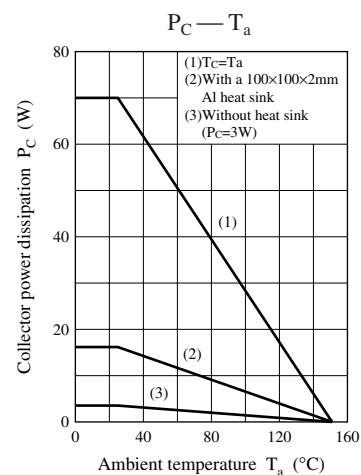
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Base-emitter voltage	V_{BE}	$V_{CE} = -5\text{ V}, I_C = -4\text{ A}$			-1.8	V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -120\text{ V}, I_E = 0$			-50	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -3\text{ V}, I_C = 0$			-50	μA
Forward current transfer ratio	h_{FE1}	$V_{CE} = -5\text{ V}, I_C = -20\text{ mA}$	20			—
	h_{FE2}^*	$V_{CE} = -5\text{ V}, I_C = -1\text{ A}$	60		200	
	h_{FE3}	$V_{CE} = -5\text{ V}, I_C = -4\text{ A}$	20			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -4\text{ A}, I_B = -0.4\text{ A}$			-2.0	V
Transition frequency	f_T	$V_{CE} = -5\text{ V}, I_C = -0.5\text{ A}, f = 1\text{ MHz}$		15		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$		150		pF

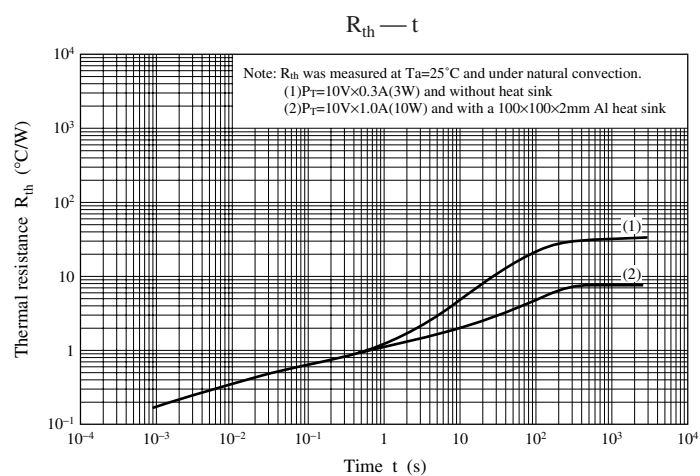
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Q	S	P
h_{FE2}	60 to 120	80 to 160	100 to 200







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